



DMN3042L

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> max	I <sub>D</sub> max
2014	26.5mΩ @ V <sub>GS</sub> = 10V	5.8A
30V	32mΩ @ V <sub>GS</sub> = 4.5V	5.0A

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(on)})$  and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Battery charging
- Power management functions
- DC-DC converters
- Portable power adaptors

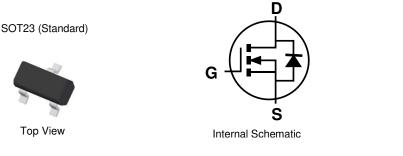
## Features and Benefits

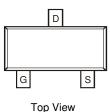
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

N-CHANNEL ENHANCEMENT MODE MOSFET

## **Mechanical Data**

- Package: SOT23 (Standard)
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Annealed over Copper Lead-Frame. Solderable per MIL-STD-202, Method 208 (3)
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)





## **Ordering Information**

Part Number	Package	Packing		
Part Nulliper	Раскауе	Qty.	Carrier	
DMN3042L-7	SOT23 (Standard)	3,000	Tape & Reel	
DMN3042L-13	SOT23 (Standard)	10,000	Tape & Reel	

Notes: 1. N

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

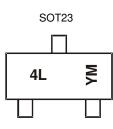
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



## **Marking Information**



 $\begin{array}{l} 4L = Product Type Marking Code \\ YM = Date Code Marking \\ Y \ or \ \overline{Y} = Year \ (ex: I = 2021) \\ M \ or \ \overline{M} = Month \ (ex: 9 = September) \end{array}$ 

### Date Code Key

Year	2017		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	E			J	K	L	М	Ν	0	Р	R	S
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

## Maximum Ratings (@ T<sub>A</sub> = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V <sub>DSS</sub>	V			
Gate-Source Voltage			V <sub>GSS</sub>	±12	V
Continuous Drain Current (Note 6) $V_{GS}$ = 10V	ID	5.8 4.0	А		
Maximum Body Diode Forward Current (Note 6)	Is	1.5	А		
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I <sub>DM</sub>	30	А		

# **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5)		PD	0.72	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0JA</sub>	171	°C/W
Power Dissipation (Note 6)	·	PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	93	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C



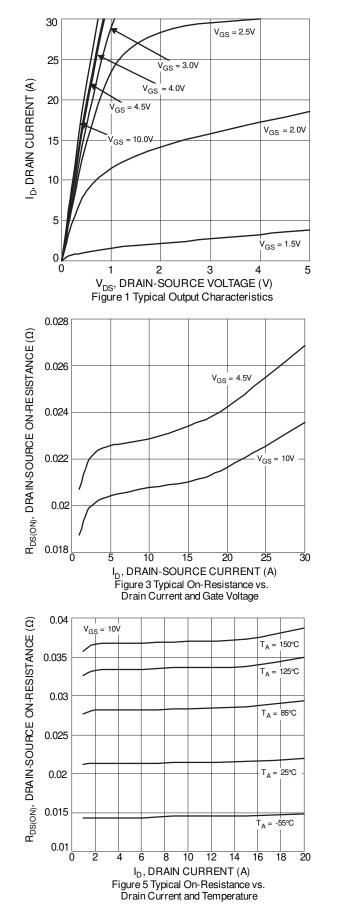
Notes:

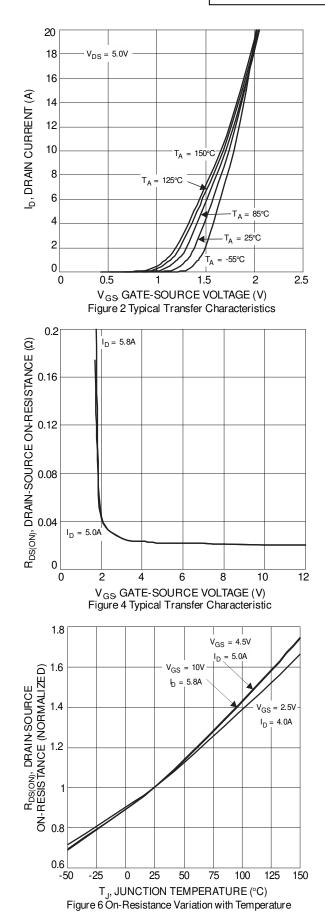
## Electrical Characteristics (@ T<sub>A</sub> = +25°C unless otherwise specified.)

Characteristic	Cumhal	Min	Turn	Мах	فأحدل	Test Condition
	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)			r	1		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	—		V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		—	1	μΑ	$V_{DS} = 30V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.6	—	1.4	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
		_	21	26.5		$V_{GS} = 10V, I_D = 5.8A$
Static Drain-Source On-Resistance	R <sub>DS(on)</sub>	_	23	32	mΩ	$V_{GS} = 4.5V, I_D = 5.0A$
			29	48		$V_{GS} = 2.5V, I_D = 4.0A$
Diode Forward Voltage	V <sub>SD</sub>		0.7	1.2	V	$V_{GS} = 0V, I_S = 1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	570	860		$V_{DS} = 15V, V_{GS} = 0V$ f = 1.0MHz
Output Capacitance	C <sub>oss</sub>	_	63	95	pF	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	53	80		
Gate Resistance	R <sub>G</sub>	_	3.2	4.5	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	13.3	20		
Total Gate Charge ( $V_{GS} = 4.5V$ )	Qg	_	6.1	8	nC	
Gate-Source Charge	Q <sub>gs</sub>	_	1.0	1.5	10	$V_{DS} = 15V, I_D = 6.9A$
Gate-Drain Charge	Q <sub>gd</sub>		1.6	2.5		
Turn-On Delay Time	t <sub>D(on)</sub>	_	1.5	2.4		$V_{GS} = 10V, V_{DD} = 15V, R_G = 3\Omega,$ $I_D = 6.9A$
Turn-On Rise Time	tr	_	3.3	5	nS	
Turn-Off Delay Time	t <sub>D(off)</sub>		13.9	22	113	
Turn-Off Fall Time	t <sub>f</sub>		4.9	7	1	
Body Diode Reverse Recovery Time	t <sub>rr</sub>		7.8	12	nS	I <sub>S</sub> = 5A, dI/dt = 100A/µs
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	_	1.9	3	nC	I <sub>S</sub> = 5A, dI/dt = 100A/µs

Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

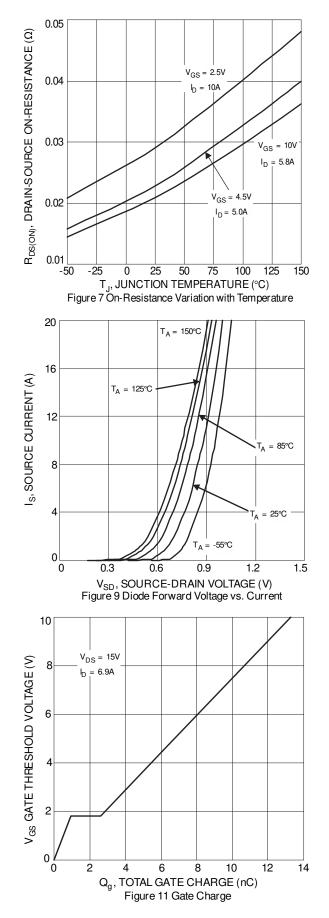


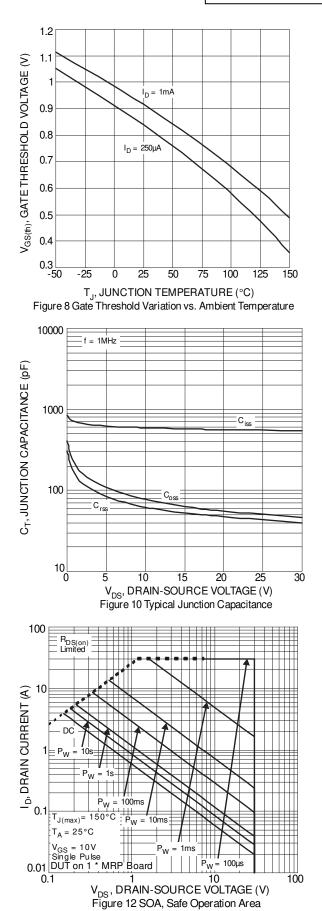




DMN3042L Document number: DS37539 Rev. 4 - 2

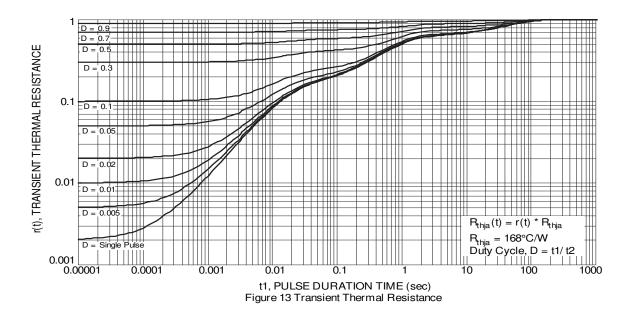






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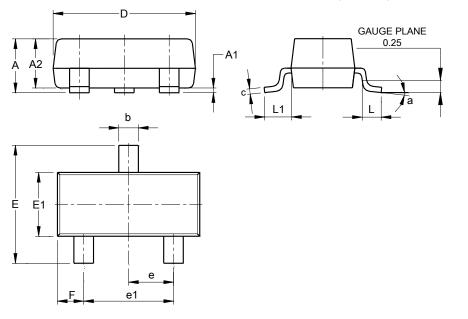






# **Package Outline Dimensions**

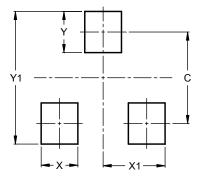
Please see http://www.diodes.com/package-outlines.html for the latest version.



### SOT23 (Standard)

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

SOT23 (Standard)

Max

1.15

0.10

1.10

0.51

0.202

3.00

2.55

1.40

1.03

2.05

0.60

0.61

0.55

8°

All Dimensions in mm

Тур

1.025

0.05

0.975

0.40

0.11

2.90

2.40

1.30

0.915

1.83

0.535

0.55

0.40

Dim Min

A A1

A2

b

С

D

Ε

E1

е

e1 F

L1

L

а

0.90

0.00

0.85

0.30

0.080

2.80

2.25

1.20

0.89

1.78

0.40

0.45

0.25

0°



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